

10/634,917



Docket No.: 241189US2S



ATTORNEYS AT LAW

COMMISSIONER FOR PATENTS  
ALEXANDRIA, VIRGINIA 22313

RE: Inventor: Wataru SAITO, et al.

Patent No.: 6,940,090 *B2*

Issued: September 6, 2005

Group Art Unit: 2822

Examiner: LEWIS, Monica

For: A WIDEBAND GAP POWER SEMICONDUCTOR  
DEVICE HAVING A LOW ON-RESISTANCE AND  
HAVING A HIGH AVALANCHE CAPABILITY  
USED FOR POWER CONTROL.

SIR:

Attached hereto for filing are the following papers:

**REQUEST FOR CERTIFICATE OF CORRECTION**  
**CERTIFICATE OF CORRECTION FORM PTO 1050**

Our check in the amount of \$0.00 is attached covering any required fees. In the event any variance exists between the amount enclosed and the Patent Office charges for filing the above-noted documents, including any fees required under 37 C.F.R. 1.136 for any necessary Extension of Time to make the filing of the attached documents timely, please charge or credit the difference to our Deposit Account No. 15-0030. A duplicate copy of this sheet is enclosed.

Respectfully submitted,

OBLON, SPIVAK, McCLELLAND,  
MAIER & NEUSTADT, P.C.

*Joseph Scafetta Jr.*  
Marvin J. Spivak

Registration No. 24,913

Joseph Scafetta, Jr.

Registration No. 26,803

Customer Number

**22850**

Tel. (703) 413-3000  
Fax. (703) 413-2220  
(OSMMN 05/04)

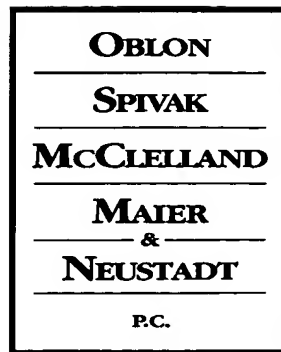
**Certificate**  
**NOV 01 2005**  
**of Correction**

**NOV 02 2005**



Docket No.: 241189US2S

COMMISSIONER FOR PATENTS  
ALEXANDRIA, VIRGINIA 22313



ATTORNEYS AT LAW

RE: Inventor: Wataru SAITO, et al.

Patent No.: 6,940,090 B2

Issued: September 6, 2005

Group Art Unit: 2822

Examiner: LEWIS, Monica

For: A WIDEBAND GAP POWER SEMICONDUCTOR  
DEVICE HAVING A LOW ON-RESISTANCE AND  
HAVING A HIGH AVALANCHE CAPABILITY  
USED FOR POWER CONTROL.

SIR:

Attached hereto for filing are the following papers:

**REQUEST FOR CERTIFICATE OF CORRECTION**  
**CERTIFICATE OF CORRECTION FORM PTO 1050**

Our check in the amount of \$0.00 is attached covering any required fees. In the event any variance exists between the amount enclosed and the Patent Office charges for filing the above-noted documents, including any fees required under 37 C.F.R. 1.136 for any necessary Extension of Time to make the filing of the attached documents timely, please charge or credit the difference to our Deposit Account No. 15-0030. A duplicate copy of this sheet is enclosed.

Respectfully submitted,

OBLON, SPIVAK, McCLELLAND,  
MAIER & NEUSTADT, P.C.

  
Marvin J. Spivak

Registration No. 24,913

Joseph Scafetta, Jr.  
Registration No. 26,803

Customer Number

**22850**

Tel. (703) 413-3000  
Fax. (703) 413-2220  
(OSMMN 05/04)

NOV 02 2005

DOCKET NO.: 241189US2S/amr



**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

IN RE APPLICATION OF: Wataru SAITO, et al.

PATENT NO.: 6,940,090 B2

GROUP: 2822

ISSUED: September 6, 2005

EXAMINER: LEWIS, Monica

FOR: A WIDEBAND GAP POWER SEMICONDUCTOR DEVICE HAVING A LOW ON-RESISTANCE AND HAVING A HIGH AVALANCHE CAPABILITY USED FOR POWER CONTROL.

**REQUEST FOR CERTIFICATE OF CORRECTION**

DIRECTOR OF THE UNITED STATES PATENT AND TRADEMARK OFFICE  
ALEXANDRIA, VA 22313-1450

SIR:

The following is a Request for a Certificate of Correction in Serial Number 10/634,917, now Patent Number 6,940,090.

In accordance with the provisions of Rule 322 of the Rules of Practice, which implement 35 USC 254, the Patent & Trademark Office is respectfully requested to issue a Certificate of Correction in the above-identified patent.

In light of the fact that the errors were the fault of the Patent & Trademark Office, no fees are required. The requested corrections are listed on FORM P.T.O. 1050.

Respectfully submitted,

OBLON, SPIVAK, McCLELLAND,  
MAIER & NEUSTADT, P.C.

Marvin J. Spivak

Registration No. 24,913

Joseph Scafetta, Jr.

Registration No. 26,803

Customer Number

**22850**

Tel. (703) 413-3000  
Fax. (703) 413-2220  
(OSMMN 05/05)

NOV 02 2005

UNITED STATES PATENT AND TRADEMARK OFFICE  
**CERTIFICATE OF CORRECTION**

PATENT NO. : **6,940,090 B2**  
DATED: **Sep. 6, 2005**  
INVENTOR(S): **Saito et al.**

It is certified that an error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

On the title page, Item (54) and Column 1, the Title is incorrect. Item (54) and Column 1 should read:

**-- (54) A WIDEBAND GAP POWER SEMICONDUCTOR DEVICE HAVING A LOW ON-RESISTANCE AND HAVING A HIGH AVALANCHE CAPABILITY USED FOR POWER CONTROL.--**

Mailing address of sender:

Patent No. **6,940,090**

Customer Number  
**22850**

No. of add'l copies  
@ .30 per page

Tel. (703) 413-3000  
Fax. (703) 413-2220  
(OSMMN 03/02)



NOV 02 2005

UNITED STATES PATENT AND TRADEMARK OFFICE  
**CERTIFICATE OF CORRECTION**

PATENT NO. : 6,940,090 *β2*

DATED: Sep. 6, 2005

INVENTOR(S): Saito et al.

It is certified that an error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

On the title page, Item (54) and Column 1, the Title is incorrect. Item (54) and Column 1 should read:

**-- (54) A WIDEBAND GAP POWER SEMICONDUCTOR DEVICE HAVING A LOW ON-RESISTANCE AND HAVING A HIGH AVALANCHE CAPABILITY USED FOR POWER CONTROL.--**

Mailing address of sender:

Customer Number

**22850**

Tel. (703) 413-3000  
Fax. (703) 413-2220  
(OSMMN 03/02)

Patent No. 6,940,090

No. of add'l copies  
@ .30 per page



NOV 02 2005